

# Fast-Response Single-Nanowire Photodetector Based on ZnO-WS<sub>2</sub> Core-Shell Nanowire Heterostructures

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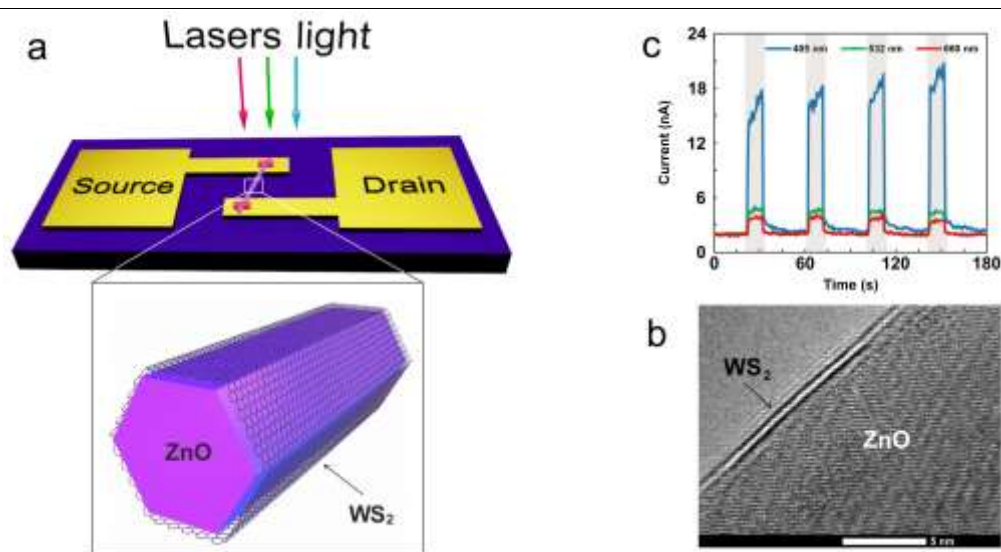
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The surface plays an exceptionally important role in nanoscale materials, exerting a strong influence on their properties. Consequently, even a very thin coating can greatly improve the optoelectronic properties of nanostructures by modifying the light absorption and spatial distribution of charge carriers. To use these advantages, ZnO-WS<sub>2</sub> core/shell nanowires with a few layers thick WS<sub>2</sub> shell were fabricated. These heterostructures were thoroughly characterized by scanning and transmission electron microscopy, X-ray diffraction, and Raman spectroscopy. Then, a single-nanowire photoresistive device was assembled by mechanically positioning ZnO-WS<sub>2</sub> core-shell nanowires onto gold electrodes inside a scanning electron microscope. The results show that a few layers of WS<sub>2</sub> significantly enhance the photosensitivity in the short wavelength range and drastically (almost 2 orders of magnitude) improve the photoresponse time of pure ZnO nanowires. The fast response time of ZnO-WS<sub>2</sub> core-shell nanowire was explained by electrons and holes sinking from ZnO nanowire into WS<sub>2</sub> shell, which serves as a charge carrier channel in the ZnO-WS<sub>2</sub> heterostructure. First-principles calculations suggest that the interface layer *i*-WS<sub>2</sub>, bridging ZnO nanowire surface and WS<sub>2</sub> shell, might play a role of energy barrier, preventing the backward diffusion of charge carriers into ZnO nanowire.

## References

- [1] E. Butanovs, S. Vlassov, A. Kuzmin, S. Piskunov, J. Butikova, B. Polyakov. Fast-response single-nanowire photodetector based on ZnO/WS<sub>2</sub> core/shell heterostructures. *ACS Appl. Mater. Interfaces*. 10, 13869-13876 (2018)
- [2] B. Polyakov, K. Smits, A. Kuzmin, J. Zideluns, E. Butanovs, J. Butikova, S. Vlassov, S. Piskunov, Y. Zhukovskii. Unexpected epitaxial growth of a few WS<sub>2</sub> layers on {11-00} facets of ZnO nanowires. *J. Phys. Chem. C*. 120, 21451-21459 (2016)



Figures

**Figure 1:** Schematics of ZnO-WS<sub>2</sub> core-shell nanowire-based photodetector (a). TEM image of a ZnO-WS<sub>2</sub> core-shell nanowire (b). On-off photoresponse measurements of ZnO-WS<sub>2</sub> nanowire at 1 V bias voltage and light illumination using 0.5 W/cm<sup>2</sup> light intensity of 405, 532, and 660 nm wavelengths (c).